



Form PTO-1449

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APPLICANT

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INFORMATION DISCLOSURE STATEMENT **BY APPLICANT**

(Use several sheets if necessary)

U.S. PATENT DOCUMENTS

Examiner Initial		Document Number	Date	Name		Class	Subclass	Filing Date
XIIM AA		4,239,661	12/16/80	Muraoka et al.	438	←252 -	-541->	471
	AB	4,958,061	09/18/90	Wakabayashi et al.		219	411	
	AC	5,286,678	02/15/94	Rastogi	438	← 4 37	-200 →	301
	AD	5,288,651	02/22/94	Nakazawa	438	< 437-	-31->	145
	AE	5,290,361	03/01/94	Hayashida et al.		134	2	
	AF	5,447,568	09/05/95	Hayakawa et al.	118	(437 -	-187→	715
	AG	5,466,389	11/14/95	Ilardi et al.	510	←252	-156-	175
	AH	5,783,495	07/21/98	Li et al.		438	738	
	AI	5,972,862	10/26/99	Torii et al.		510	175	
	AJ	5,855,811	01/05/99	Grieger et al.		252	79.3	
1	AK	5,679,171	10/1997	Saga et al.		134	3	
1	AL	6,096,650	08/2000	Robinson et al.		438	689	

FOREIGN PATENT DOCUMENTS

Examiner Initial		Document Number	Date	Country	Class	Subclass	Translation	
							Yes	No
often	AM	03-109732-A	05/1991	Japan	H01L	21/304		
1		04-101418-A	04/1992	Japan	H01L	21/304		
		07-153728-A	06/1995	Japan	H01L	21/304		
		08-250461-A	09/1996	Japan	H01L	21/304		
		08-306650-A	11/1996	Japan	H01L	21/304		
		08-306651-A	11/1996	Japan	H01L	21/304		
		09-286999-A	11/1997	Japan	H01L	21/304		

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

		O'III DOCUMENTO (Including states)				
Stal	AN	Oimet et al., "Defect Reduction and Cost Savings through Re-Inventing RCA Cleans", IEEE/SEMI Advanced Semiconductor Manufacturing Conference (1996), p. 308-313				
	AO	Watanabe et al., "Influence of particles/impurity metals in RCA cleaning solutions on surface contamination", International Symposium on Semiconductor Manufacturing (1994), pp. 99-102				
	AP	Osaka and Hattori, "Influence of Initial Wafer Cleanliness on Metal Removal Efficiency in Immersion SC-1 Cleaning: Limitation of Immersion-Type Wet Cleaning", <i>IEEE Trans. on Semiconductor Manufacturing</i> , Vol. 11, No. 1 (02/1998), pp. 20-24				
	AQ	Ridley, Sr. et al., "Advanced Aqueous Wafer Cleaning in Power Semiconductor Device Manufacturing", IEEE/SEMI Adv. Semiconductor Man. Conf. (1998), pp. 235-242				
	AR	"Improved Organic Clean for Removing Contaminants on Semiconductor Wafer Surfaces", IBM Tech. Dis. Bulletin, March 1985				
V	AS	"Improvements to MOS Retention Time Based Tests", IBM Tech. Dis. Bulletin, May 1984				
Examine	er	Date Considered				

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11-8-2001